

10A 650V N Channel MOSFET

Features

- $V_{DS} = 650V$
- $I_D = 10A @V_{GS} = 10V$
- $R_{DS(ON)} (Typ) = 0.75\Omega @V_{GS} = 10V$

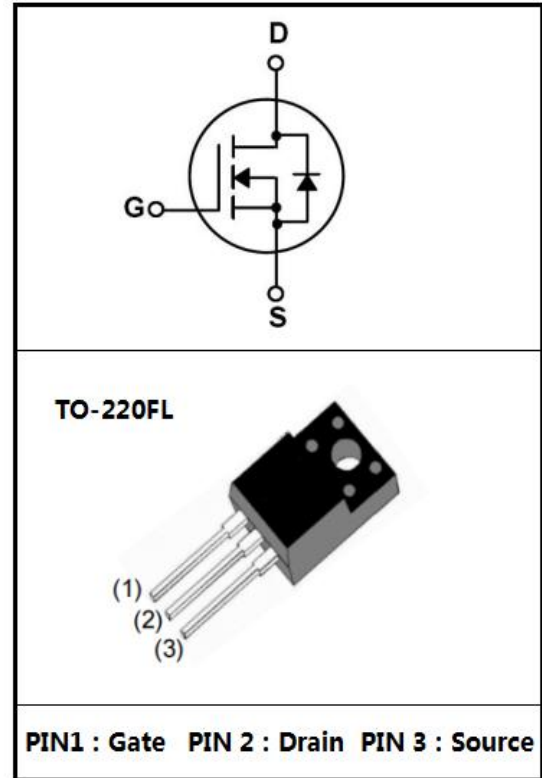
Applications

- Power Supply
- PFC
- High Current, High Speed Switching

Descriptions

These N-channel MOSFET are produced using advanced plane MOSFET Technology, which provides Low on-state resistance, high switching performance and excellent quality.

These devices are suitable device for SMPS, high Speed switching and general purpose applications.



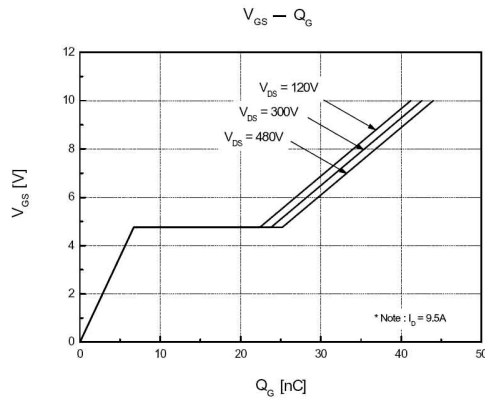
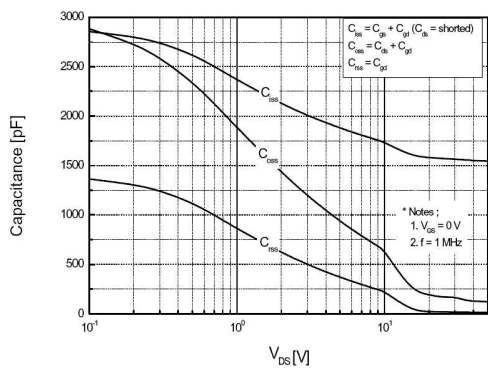
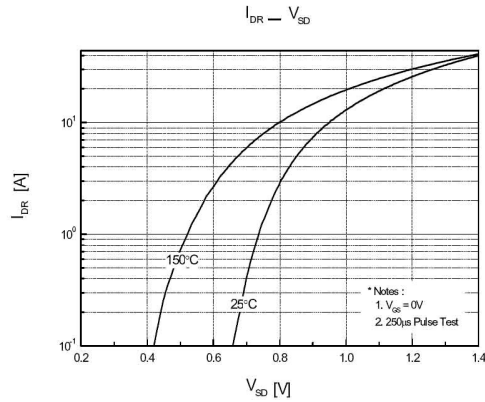
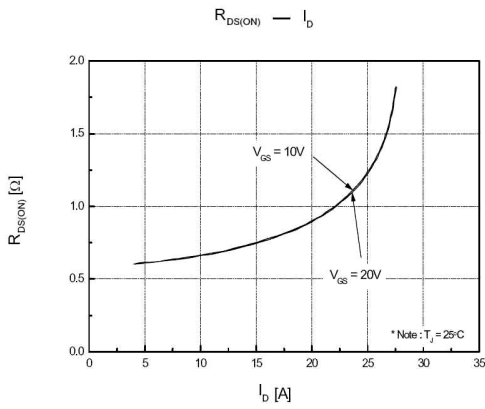
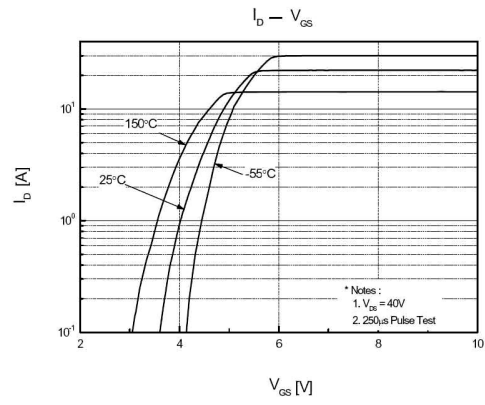
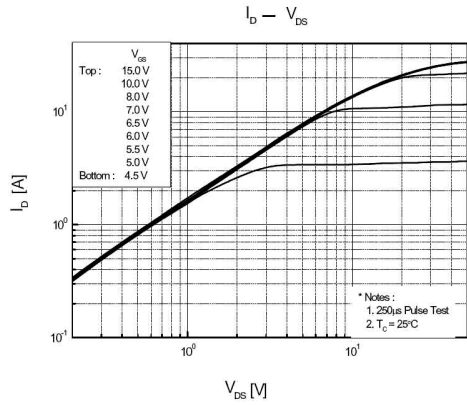
Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DSS}	650	V
Drain Current	$I_D(T_C=25^\circ\text{C})$	10	A
Drain Current	$I_D(T_C=100^\circ\text{C})$	5.7	A
Drain Current - Pulsed	I_{DM}	38	A
Gate-Source Voltage	V_{GSS}	± 30	V
Single Pulsed Avalanche Energy	E_{AS}	700	mJ
Repetitive Avalanche Energy	E_{AR}	15.6	mJ
Avalanche Current	I_{AR}	9.5	A
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.5	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C}/\text{W}$
Power Dissipation	$P_D(T_C=25^\circ\text{C})$	50	W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to 150	$^\circ\text{C}$

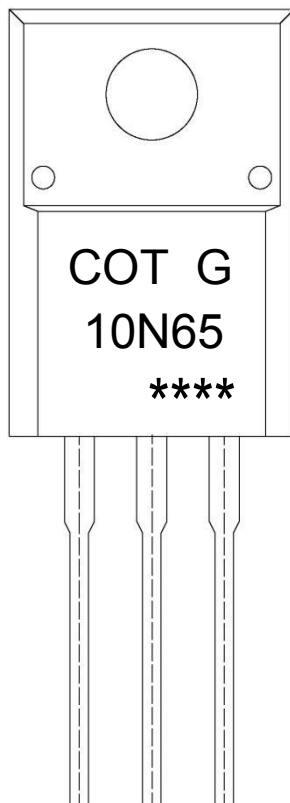
Electrical Characteristics(Ta=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=250\mu A$	650			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=600V$ $V_{GS}=0V$			1.0	μA
		$V_{DS}=480V$ $T_C=125^\circ\text{C}$			10	μA
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 30V$ $V_{DS}=0V$			± 10	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	2.0		4.0	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=4.75A$		0.75	0.85	Ω
Forward Transconductance	g_{FS}	$V_{DS}=40V$ $I_D=4.75A$		8.0		S
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=9.5A$			1.4	V
Input Capacitance	C_{iss}	$V_{DS}=25V$ $V_{GS}=0V$ $f=1.0\text{MHz}$		1570	2040	pF
Output Capacitance	C_{oss}			166	215	pF
Reverse Transfer Capacitance	C_{rss}			18	24	pF
Turn-On Delay Time	$t_{d(on)}$				23	55
Turn-On Rise Time	t_r	$V_{DD}=300V$ $I_D=9.5A$ $R_G=25\Omega$		69	150	ns
Turn-Off Delay Time	$t_{d(off)}$			144	300	ns
Turn-Off Fall Time	t_f			77	165	ns

Electrical Characteristic Curve



Marking Instructions



Note:

COT: Company Logo

G: Halogen Free

10N65: Product Type.

****: Lot No. Code, code change with Lot No.

Packaging SPEC.

TUBE INFORMATION

Package Type	Units					Dimension (unit: mm ³)		
	Units/Tube	Tubes/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Tube	Inner Box	Outer Box
TO-220FL	50	20	1,000	5	5,000	532×33×7.0	555×164×50	575×290×180

Package Outline Dimensions

TO-220FL

单位: mm

